14.1-7 ON THE THEORY OR N-BEAM LATPICE TMAGE FORMATION IN HREM ON THE BASIS OF THE BLOCH WAVE FORMALISM. BY F.N.Chukhovskii and V.I. Vergesov, Institute of Grystallography, Acedemy of Sciences of the USSR, Moscow, USSR.
Alattice image in HREM is fomed provided the N-beam symmetrical diffraction of fast electrons in crystal occurs, which is described by the dynamical matrix of the $N$-th rang ( $N \gg 1$ ). It means that for determining proper wave vectors of electron Bloch waves the dispersion equation can be in general solved only numerically. In this report the analytical approach to the lattice image formation is developed by use of the Bloch wave function formalism. In practice of $H R E M$ the diffraction pattern and the dynamical matrix have the symmetry of one of the two-dimensional point groups, which allows to reduce the dispersion equation order essentially (Kogiso and Talranashi, J. Phys. Soc. Jap. (1977) 42, 223; Vergasov, Chukhovskii and Pinsker, Kristallograiia (1982) 27 . 645). In the case under consideration the electron Bloch waves excited belong only to the identity irreducible representation of the difiraction pattern group symmetry and the corresponding dispersion equation has been obtained by the present authors (Izv. Akad. Nauk SSSR, ser. fiz. (1983) 47, 1174).
In accordance with the group-theoretical method a complete set of $N$ reflections is divided into two sets: first of ones consists of $N_{0}$ "strong" reflections and the second one is represented by a number of systems of $N_{k}$ equal intensity reflections ( $\sum N_{K}=N-N_{0}$ ).
By taking into account the first set of reflections the electron Bloch wave functions can be constructed and they are an zero-order solution of the $N$-beam diffraction problem. Furthermore, the correct detemmination of the Bloch weve functions have been performed by the perturbation theory in powers of the values
$\left(J\left(N_{K}\right) / J\left(N_{0}\right)\right)^{1 / 2}$,
where $g\left(N_{K}\right)$ is the total intensity of $N_{K}$ diffrected beans. Notice that each system of $N K \neq 0$ beams corresponds to the single Bloch wave, for which the dispersion equetion is the first order one.
As an example, the 37 -beam diffraction problem (Si-crystal in orientation 〈111〉, electron energy $\mathrm{E}=100 \mathrm{keV}$ ) is studied analytically. The system of No reflections of the zero-order approximation is show in Fig. 1. For the total intensity of these reflections $J\left(N_{0}\right)$ the results of analytical and numerical calculations (dashed and solid curves, respectively) are presented in Fig.2. It is seen that:(i) the main part of the intensity of the incident beam is concentrated in $N_{0}$ reflections drawn in Fig. 1 ; (ii) analytical and numerical calculations are in a good agreement with an accuracy up to $3 \%$.


foil thickness ( A )
Fig. 1
Fig. 2
14.1-8 THE MUITIBEAM INTERACITON EFFECT ON GIECTRON DIFFRACTION IN POLYCRYSTAIS WIMH A DIFFERENT DEGREE OF ORIENTATION OF NICROCRYSTAIS. By A.S.Avilov, Institute of Crystallography, Academy of Sciences of USSR, Hoscow, USSR.
Electron diffraction analysis deals mainly with thin films which are, in fact, sets of microorystals with a different degree of orientation (mosaic single orystals, textures and polyorystals) and angular and thickness distributions. The aim of this paper was to worls out a method of calculation of reflection intensities in the case of multibeam reflections for mosaic single crystals and textures followed by thickness and orientation averaging.
The following model wes used: a thin film represented a single layer of microcrystals, each of the microcrystals scattered electrons independently, and the scattering intensity in every direction was the sum of scattered intensities of single group of crystals, oriented likewise to the incident beem and having certain thickness distribution.
Fujimoto's matrin method wes used (Fujimoto, J.Phys.Soc.Japan. (1959) 14, 1558). This method implies the obligatory caloulation of diagonal elements of a "aynamic matrix" which depend on diffraction geometry. The paper suggests the ways of caloulation of diagonal elements and intensity averaging.
The hio-reflection intensities were determined Ior mosaic Iif single crystals and compared to the experimental data (Avilov, Crystallography (1979) 24, 178). Allowing for only $50-60$ beams the divergence factor Ior intensities decreased from $32 \%$ (for kinematic approach) to $7 \%$. An analogous result was obtained for texture PbSe samples (the texture axis [001])
14. 1-9 DYNAMICAL THEORY OF MANY-BEAM SCATTERING OF FAST ELECTRONS AND ITS APPLICATION TO STRUCTURE IAVESTIGATION IN HIGH-RESOLUTION ELECTRON MICROSCOPY. By Z.G. Pinsker and F.N. Chukhovskii, Institute of Crystallography, Academy of Sciences of the USSR

By use of the group theory the many-wave problem of scattering of fast electrons in crystals is discussed. One finds that in the common case of the high-resolution electron microscopy when the electron beam is normally incident on the crystal surface in a crystallographic direction it is sufficient to solve the dispersion equation corresponding to a single irreducible representation of the symmetry group of the electron diffraction pattern. The main new results of the treatment developed are following:

1. the theorem establishing the connection of the highest degree of equation arising in factorization of the dispersion equation of the many-wave problem with the symmetry and structure of the electron diffraction pattern is proved;
2. the perturbation theory for finding electron Bloch waves is proposed.

Results of the analytical many-beam calculations for 100 keV to 1 MeV electrons incident of $\mathrm{Au}, \mathrm{Si}$, Ce crystals are given as examples. The correspondence between the results of the dynamical theory of diffraction and ones of the theory of electron channeling is considered.

## References:

V.L. Vergasov, F.N. Chukhovskii and Z.G. Pinsker, Kristallografiya (1982) 27, 449-456; 27, 645-651

